

# N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

#### **DESCRIPTION**

The 2SK1482 is N-channel vertical type MOS FET switching device which can be directly driven from an IC operating with a 5 V single power supply. The device featuring low on-state resistance is of the voltage drive type and thus is ideal for driving actuators such as motors, solenoids, and relays.

#### **FEATURES**

· Low on-state resistance

RDS(on)1 = 0.8  $\Omega$  MAX. (VGS = 4 V, ID = 0.5 A)

RDS(on)2 = 0.4  $\Omega$  MAX. (VGS = 10 V, ID = 0.5 A)

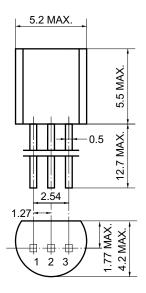
- Voltage drive at logic level (Vgs = 4 V) is possible.
- Bidirectional zener diode for protection is incorporated in between the gate and the source.
- Inductive loads can be driven without protective circuit thanks to the improved breakdown voltage between the drain and source.
- Can be used complementary with the 2SJ196.

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

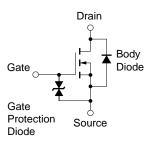
Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±1.5	Α
Drain Current (pulse) Note	D(pulse)	±3.0	Α
Total Power Dissipation (T <sub>A</sub> = 25°C)	Рт	750	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

**Note** PW  $\leq$  10 ms, Duty Cycle  $\leq$  50%

## PACKAGE DRAWING (Unit: mm)



### **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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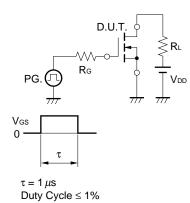
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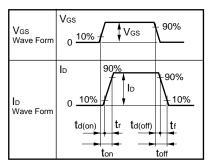


ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			10	μΑ
Gate Leakage Current	Igss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.3	1.8	2.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A	0.4			S
Drain to Source On-state Resistance	R <sub>DS(on)1</sub>	Vgs = 4.0 V, ID = 0.5 A		0.19	0.8	Ω
	R <sub>DS(on)2</sub>	Vgs = 10 V, ID = 0.5 A		0.15	0.4	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		230		pF
Output Capacitance	Coss	Vgs = 0 V		170		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		45		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 25 V, I <sub>D</sub> = 0.5 A		15		ns
Rise Time	tr	Vgs = 10 V		50		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$		420		ns
Fall Time	tf			240		ns

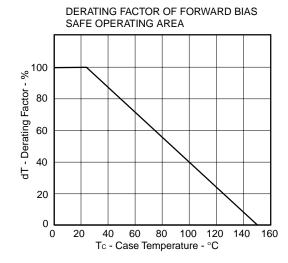
### **SWITCHING TIME**

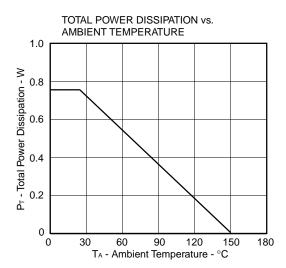


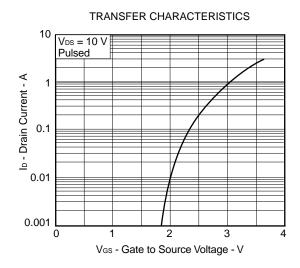


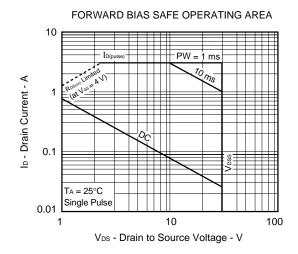


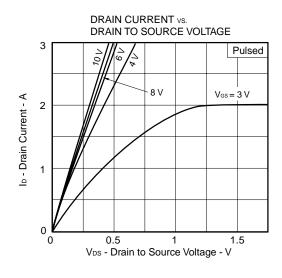
# TYPICAL CHARACTERISTICS (TA = 25°C)

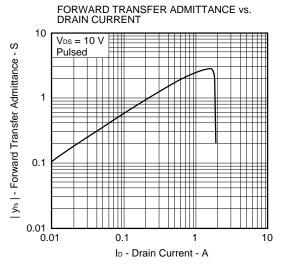


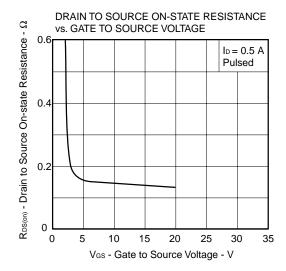


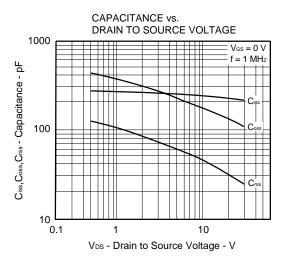




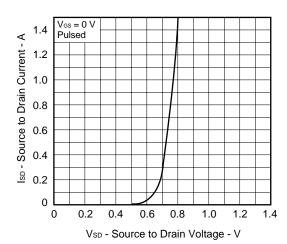


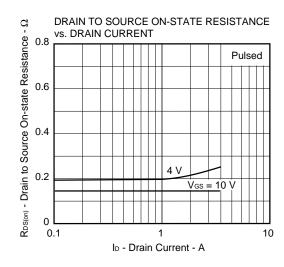


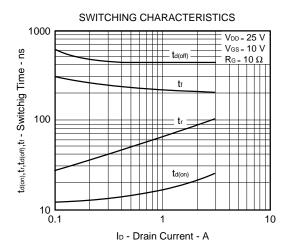




### SOURCE TO DRAIN DIODE FORWARD VOLTAGE









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